

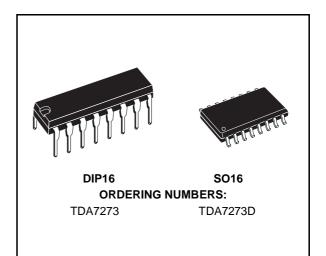
TDA7273

SINGLE CHIP STEREO CASSETTE PLAYBACK SYSTEM

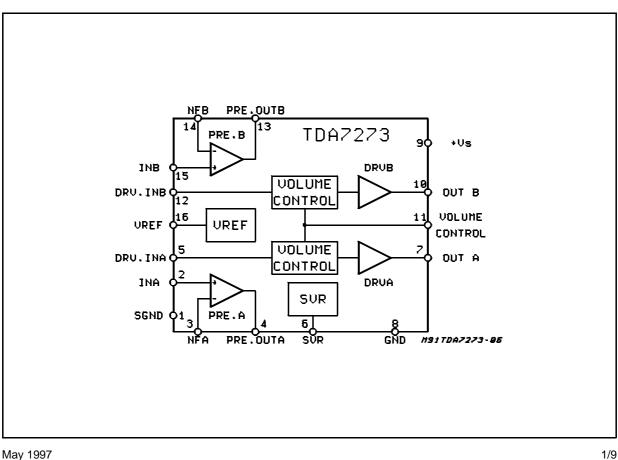
- WIDE OPERATING SUPPLY VOLTAGE (1.8V to 7V)
- INPUT COUPLING WITHOUT CAPACITORS
- BUILT-IN DC STEREO VOLUME CONTROL
- **BUILT-IN RIPPLE FILTERS**
- LOW QUIESCENT CURRENT
- NO EXTERNAL BOUCHEROT CELL
- MAX OUTPUT CURRENT 70mA PEAK

DESCRIPTION

The TDA7273 is a monolithic integrated circuit designed for portable cassette players market. It comprises preamplifiers, DC volume control, and headphone drivers.



BLOCK DIAGRAM



TDA7273

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Test Conditions	Unit
Vs	Supply Voltage	9	V
Ιo	Output Current (max)	70	mA
T _{op}	Operating Temperature Range	-20 to 70	°C
T _{stg,} T _j	Storage & Junction Temperature Range	-40 to +150	°C

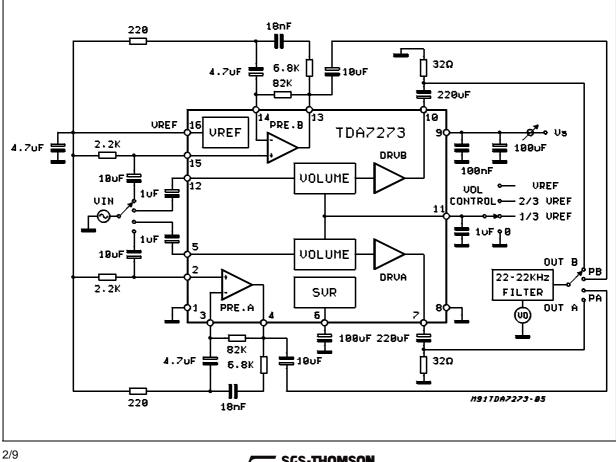
THERMAL DATA

Symbol	Description	DIP-16	SO-16	Unit
R _{thj-amb}	Thermal Resistance Junction-ambient Max	100	200	°C/W

DC CHARACTERISTICS: $T_{amb} = 25^{\circ}C$; $V_S = 3V$; $R_L = 10K\Omega$ (Preamplifier), $R_L = 32\Omega$ (Headphone); $V_{IN} = 0$; V_{OL} control = V_{ref}

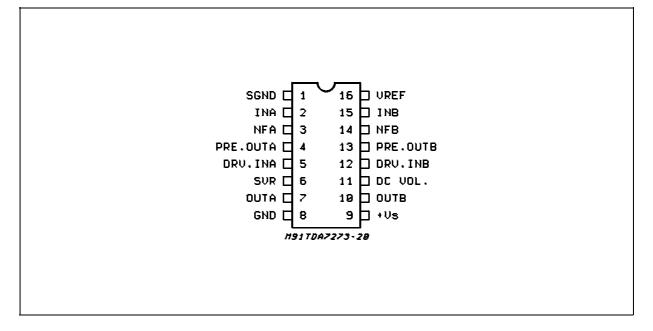
Terminal No	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
Terminal Voltage (V)	0	1.5	1.5	1.5	1.5	2.7	1.5	0	3	1.5	1.5	1.5	1.5	1.5	1.5	1.5

TEST CIRCUIT



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PIN CONNECTION (Top view)



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}C$, $V_S = 3V$, f = 1KHz, $R_L = 32\Omega$ Vol. control = $2/3V_{ref}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Voltage		1.8		7	V
l _d	Quiescent Current			14	20	mA
Vref	Reference Voltage		1.3	1.49	1.7	V

PREAMPLIFIER SECTION

G _{VO}	Open Loop Gain			70		dB
Gv	Close Loop Gain		30	33	35	dB
Vo	Output Voltage	THD = 1%	600	850		mV
I _b	Bias Current			3		μΑ
THD	Total Harmonic Distortion	V _o = 330mVrms		0.05	0.25	%
Ct	Cross Talk	$Rg = 2.2K\Omega; V_o = 330mVrms$		74		dB
E _N	Output Noise	$Rg = 2.2K\Omega$; $BW = 22Hz$ to $22KHz$		100		μV
SVR	Ripple Rejection	$\begin{array}{l} R_{g} = 2.2 K \Omega \ V_{R} = 100 mV rms \\ f = 100 Hz; \ C_{SVR} = 100 \mu F \end{array}$	40	50		dB

HEADPHONE DRIVER

V _{o(DC)}	DC Output Voltage			1.50		V
Po	Output Power	THD = 10%;	15	30		mW
Po	Transient Output Power	THD = 10% RL = 16Ω		50		mW
Gv	Close Loop Gain	$P_o = 5mW$	28	31	34	dB
THD	Total Harmonic Distortion	$P_o = 5mW$		0.2	1	%
Ct	Cross Talk	$Rg = 10K\Omega; P_o = 5mW$	40	50		dB
SVR	Ripple Rejection	$V_r = 100mVrms, f = 100Hz$ Vol. control = 1/3 V_{ref} $C_{SVR} = 100\mu$ F; $R_g = 600\Omega$		47		dB
	Volume Control Range		66	75		dB



TDA7273

Figure 1: Application Circuit

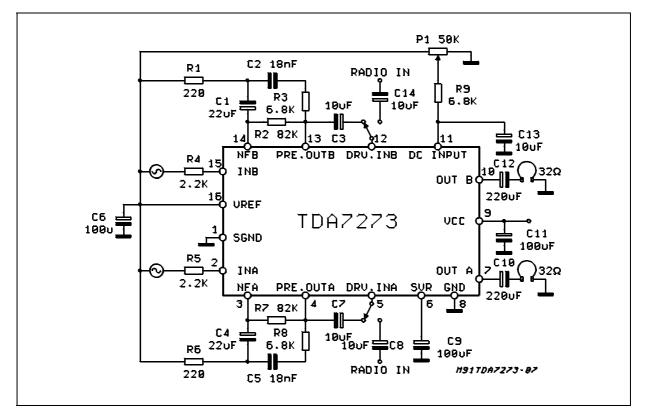


Figure 2: P.C. Board and Component Layout of the Circuit of Figure 1 (1:1 scale)

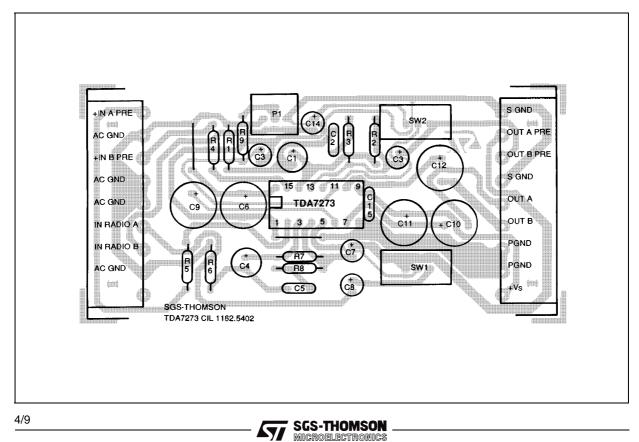
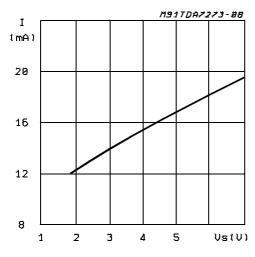
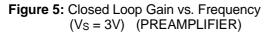
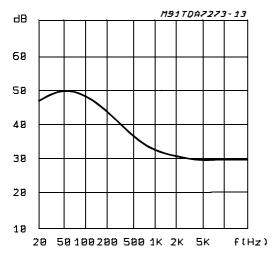


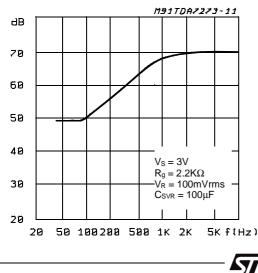
Figure 3: Supply Current vs. Supply Voltage (Preamplifier + Driver)



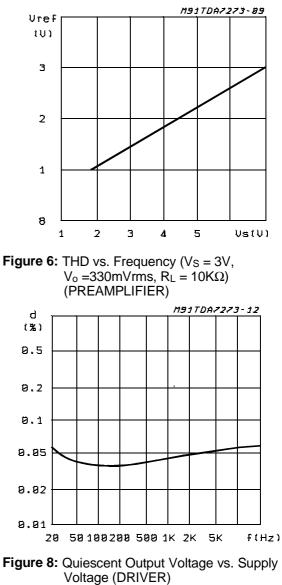




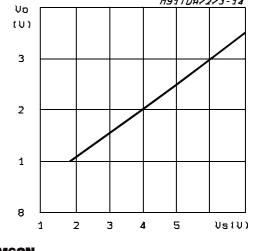




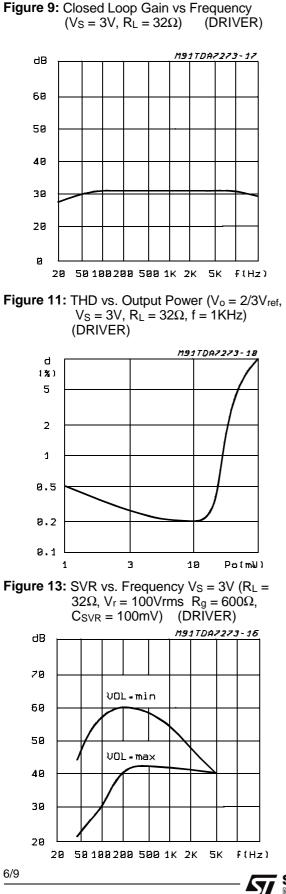


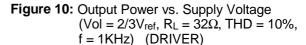


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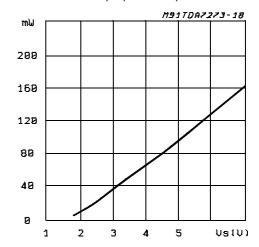


Figure 12: THD vs. Frequency ($P_o = 5mW$, $V_S = 3V R_L = 32\Omega$) (DRIVER)

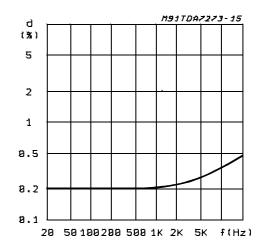
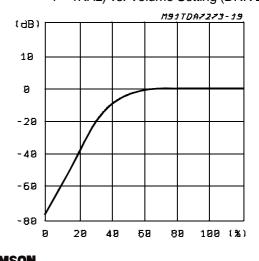


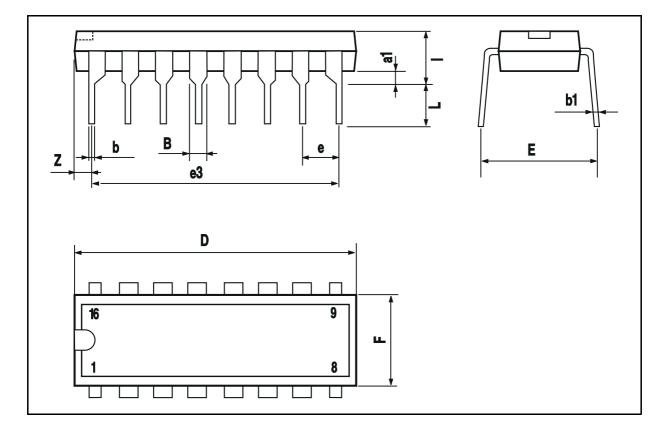
Figure 14: Volume Control (0dB = 10mW, $V_S = 3V R_{vol} = 50K\Omega$, $R_L = 32\Omega$, f = 1KHz) vs. Volume Setting (DRIVER)



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DIM.		mm				
Dini.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

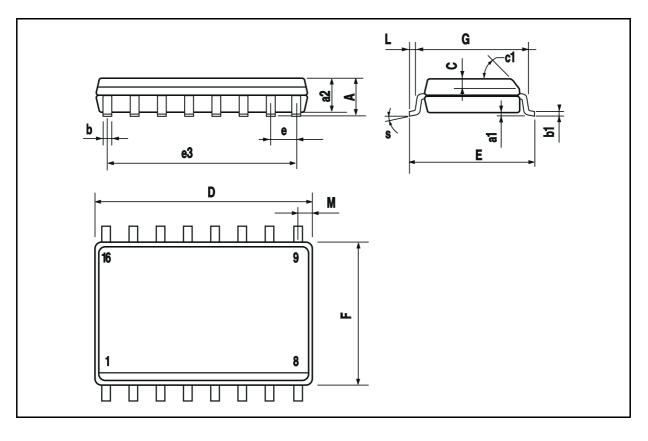
DIP16 PACKAGE MECHANICAL DATA





SO16 PACKAGE MECHANICAL DATA

DIM.		mm		inch						
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.				
А			2.65			0.104				
a1	0.1		0.2	0.004		0.012				
a2			2.45			0.096				
b	0.35		0.49	0.014		0.019				
b1	0.23		0.32	0.009		0.013				
С		0.5			0.020					
c1			45°	(typ.)						
D	10.1		10.5	0.398		0.413				
E	10.0		10.65	0.394		0.419				
е		1.27			0.050					
e3		8.89			0.350					
F	7.4		7.6	0.291		0.299				
L	0.5		1.27	0.020		0.050				
М			0.75			0.030				
S		8° (max.)								





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